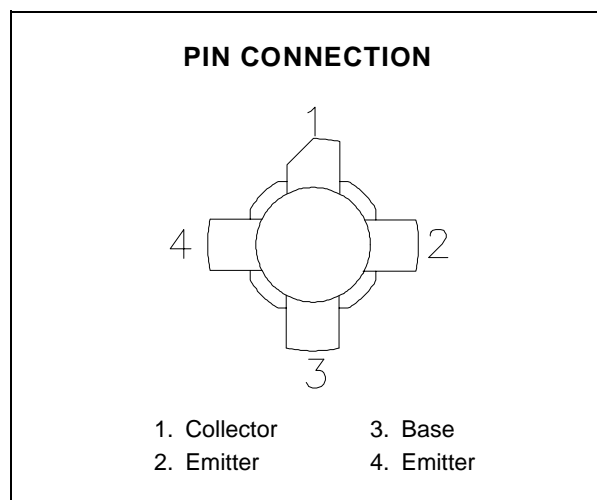
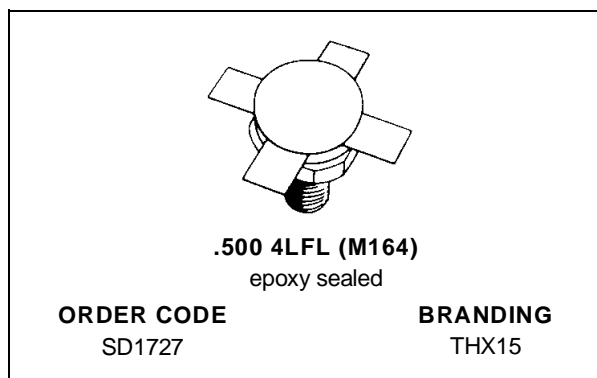


RF & MICROWAVE TRANSISTORS HF SSB APPLICATIONS

- OPTIMIZED FOR SSB
- 30 MHz
- 50 VOLTS
- IMD -30 dB
- COMMON EMITTER
- GOLD METALLIZATION
- $P_{OUT} = 150$ W PEP MIN. WITH 14 dB GAIN



DESCRIPTION

The SD1727 is a 50 V epitaxial silicon NPN planar transistor designed primarily for SSB communications. This device utilizes emitter ballasting to achieve extreme ruggedness under severe operating conditions.

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

| Symbol | Parameter | Value | Unit |
|------------|---------------------------|--------------|-------------|
| V_{CBO} | Collector-Base Voltage | 110 | V |
| V_{CEO} | Collector-Emitter Voltage | 55 | V |
| V_{EBO} | Emitter-Base Voltage | 4.0 | V |
| I_C | Device Current | 10 | A |
| P_{DISS} | Power Dissipation | 233 | W |
| T_J | Junction Temperature | +200 | $^{\circ}C$ |
| T_{STG} | Storage Temperature | - 65 to +150 | $^{\circ}C$ |

THERMAL DATA

| | | | |
|---------------|----------------------------------|------|---------------|
| $R_{TH(j-c)}$ | Junction-Case Thermal Resistance | 0.75 | $^{\circ}C/W$ |
|---------------|----------------------------------|------|---------------|

SD1727 (THX15)

ELECTRICAL SPECIFICATIONS ($T_{case} = 25^{\circ}C$)

STATIC

| Symbol | Test Conditions | | Value | | | Unit |
|------------|-----------------|---------------|-------|------|------|------|
| | | | Min. | Typ. | Max. | |
| BV_{CBO} | $I_C = 100mA$ | $I_E = 0mA$ | 110 | — | — | V |
| BV_{CES} | $I_C = 100mA$ | $V_{BE} = 0V$ | 110 | — | — | V |
| BV_{CEO} | $I_C = 100mA$ | $I_B = 0mA$ | 55 | — | — | V |
| BV_{EBO} | $I_E = 10mA$ | $I_C = 0mA$ | 4.0 | — | — | V |
| I_{CEO} | $V_{CE} = 30V$ | $I_E = 0mA$ | — | — | 5 | mA |
| I_{CES} | $V_{CE} = 60V$ | $I_E = 0mA$ | — | — | 5 | mA |
| h_{FE} | $V_{CE} = 6V$ | $I_C = 1.4A$ | 18 | — | 43.5 | — |

DYNAMIC

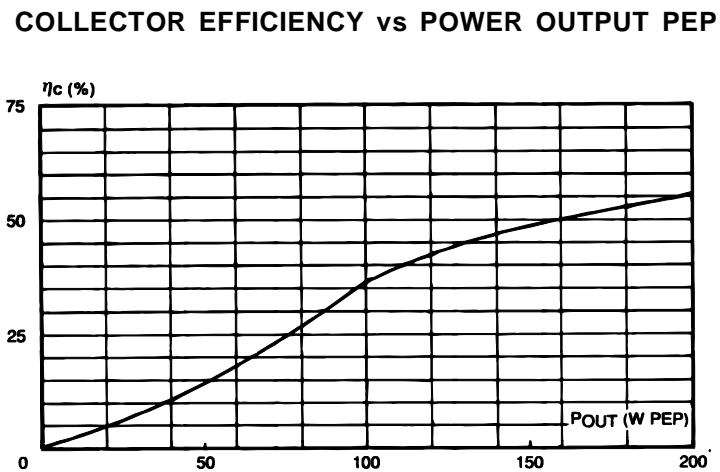
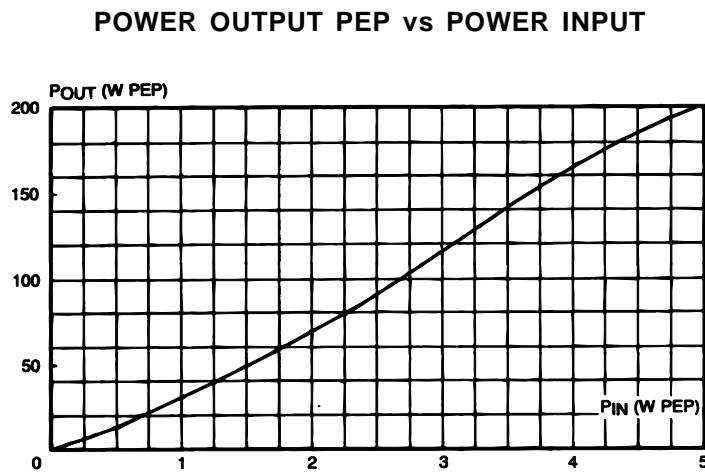
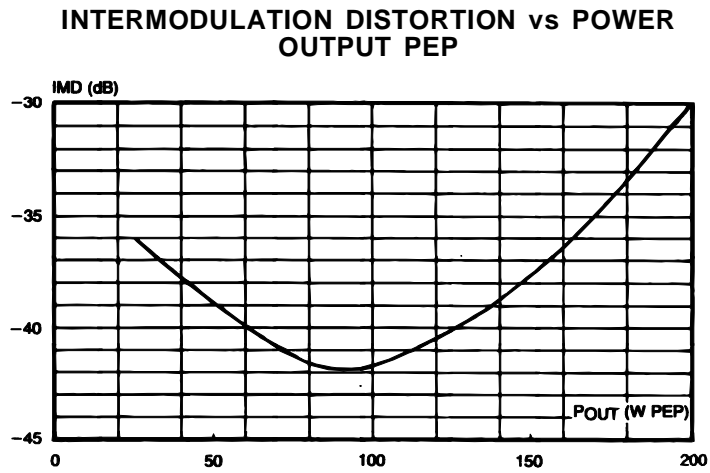
| Symbol | Test Conditions | | | Value | | | Unit |
|------------|-----------------------|-----------------|------------------|-------|------|------|------|
| | | | | Min. | Typ. | Max. | |
| P_{OUT} | $f = 30 MHz$ | $V_{CE} = 50 V$ | $I_{CQ} = 100mA$ | 150 | — | — | W |
| G_P^* | $P_{OUT} = 150 W PEP$ | $V_{CE} = 50 V$ | $I_{CQ} = 100mA$ | 14 | — | — | dB |
| IMD* | $P_{OUT} = 150 W PEP$ | $V_{CE} = 50 V$ | $I_{CQ} = 100mA$ | — | — | -30 | dBc |
| η_c^* | $P_{OUT} = 150 W PEP$ | $V_{CE} = 50 V$ | $I_{CQ} = 100mA$ | 37 | — | — | % |
| C_{OB} | $f = 1 MHz$ | $V_{CB} = 50 V$ | | — | — | 220 | pF |

Note: The SD1727 is also usable in Class A at 40 V. Typical performance is:

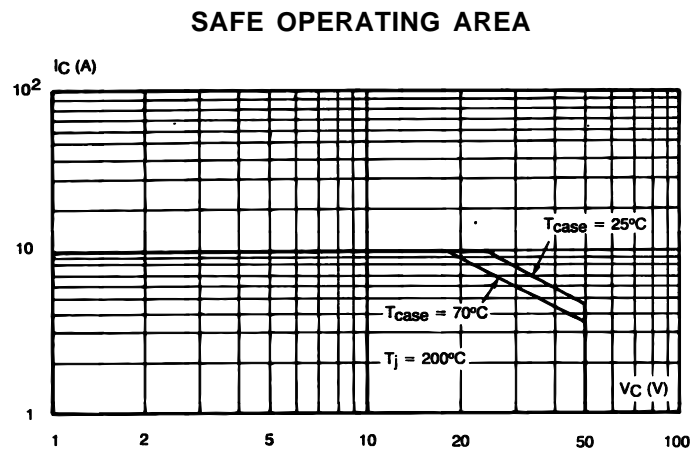
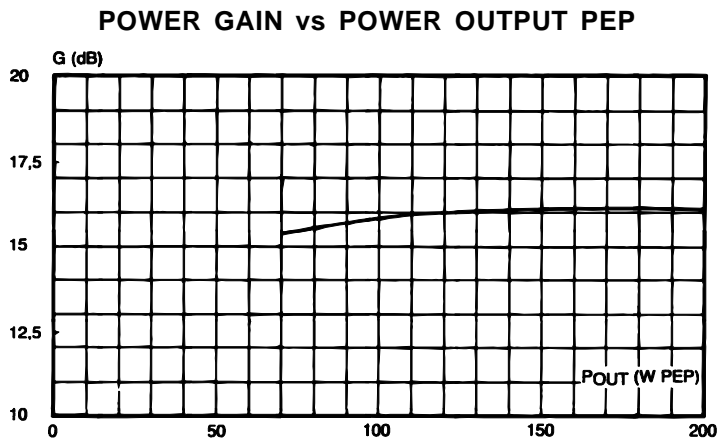
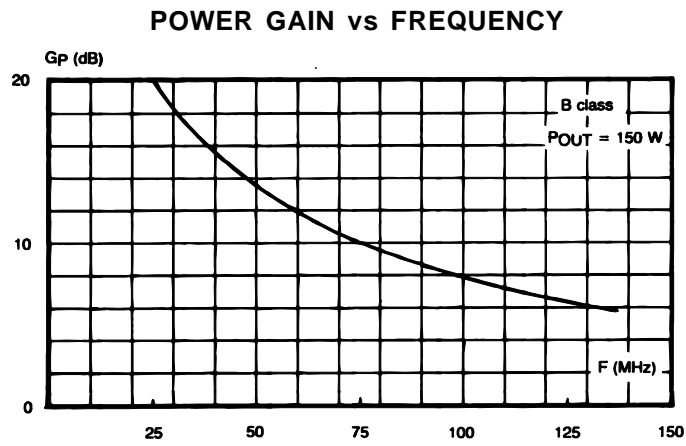
$P_{OUT} = 30 W PEP$, $G_P = 14 dB$, $IMD = -40dBc$

* $f_1 = 30.00 MHz$; $f_2 = 30.001 MHz$

TYPICAL PERFORMANCE

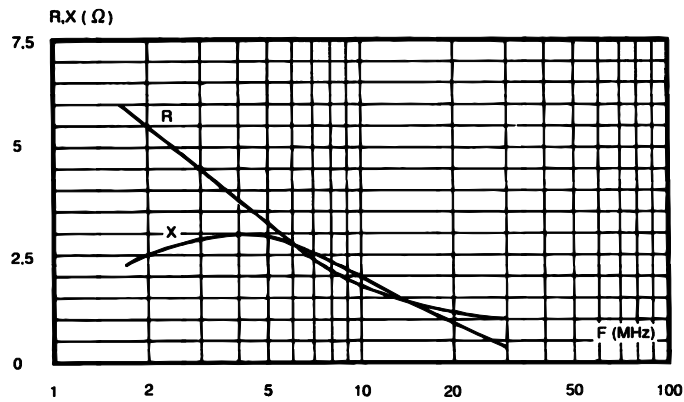


TYPICAL PERFORMANCE (cont'd)

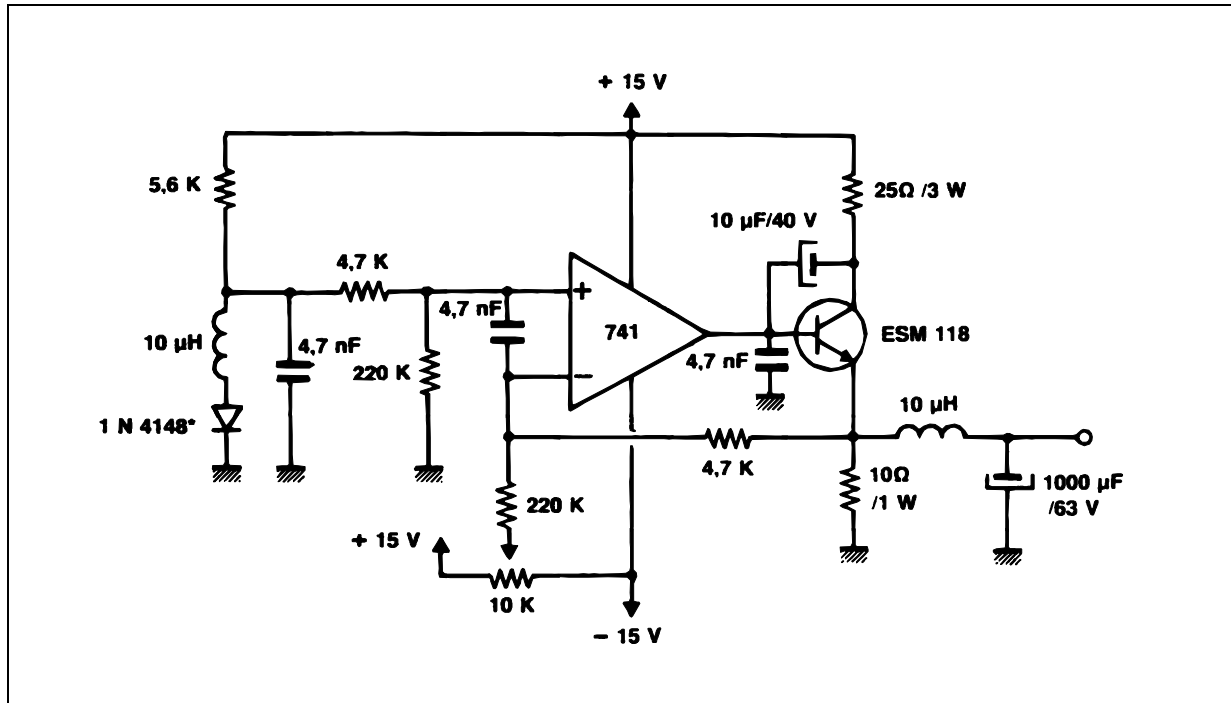


IMPEDANCE DATA

TYPICAL INPUT IMPEDANCE

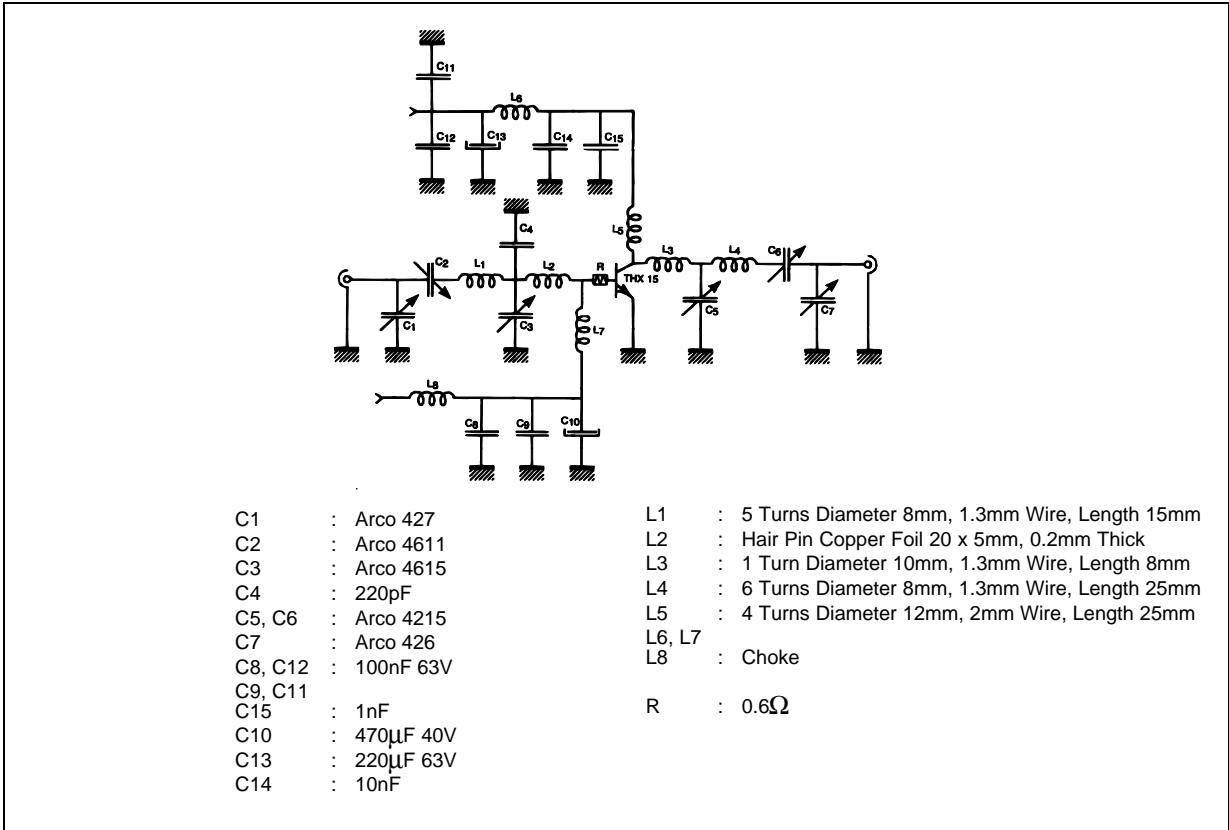


BIAS CIRCUIT

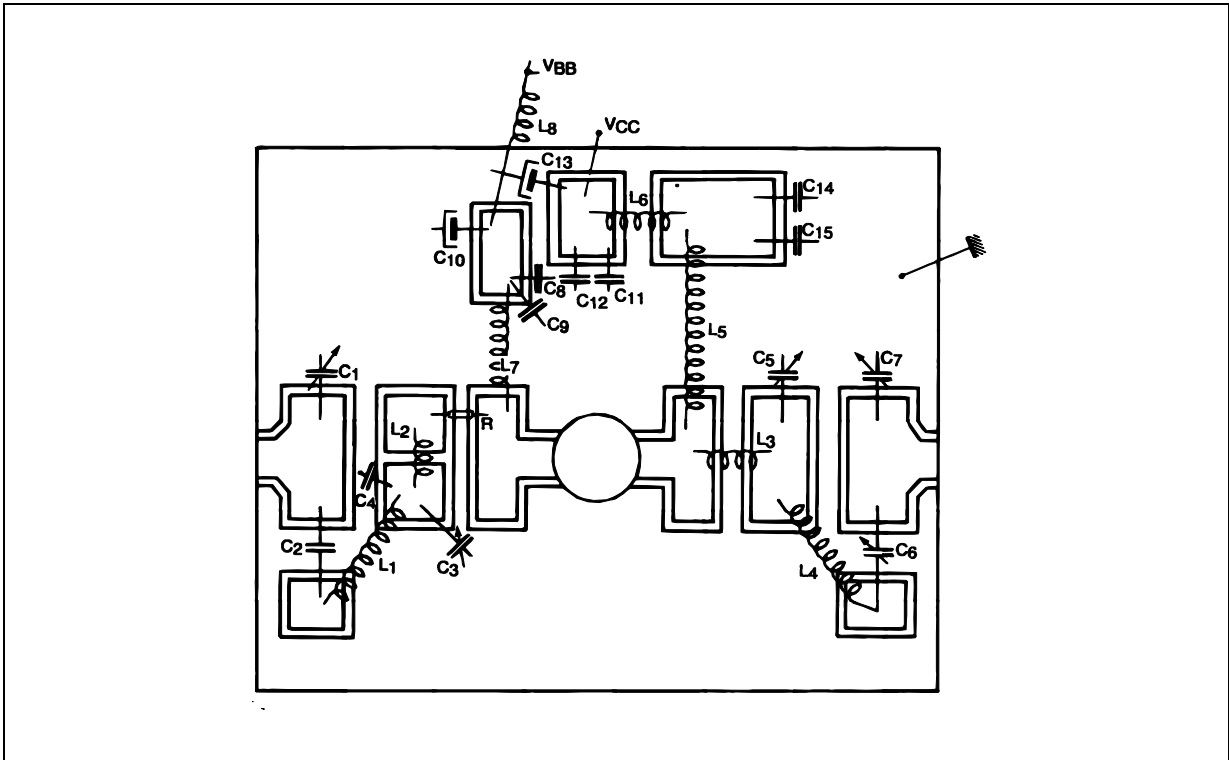


SD1727 (THX15)

TEST CIRCUIT - CLASS AB - 30 MHz

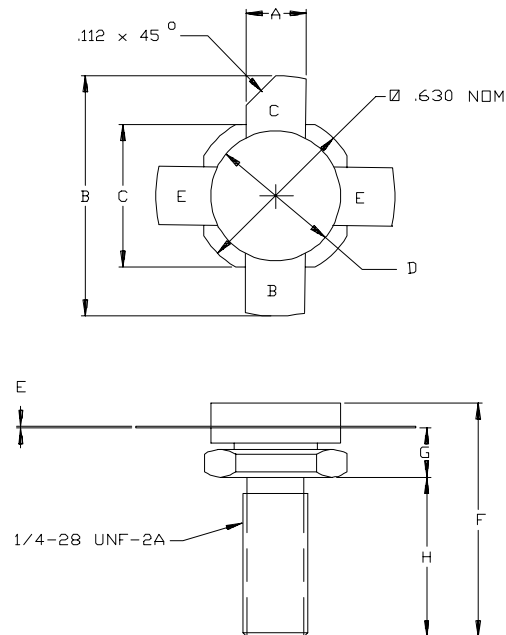


MOUNTING CIRCUIT - CLASS AB - 30MHz



PACKAGE MECHANICAL DATA

Ref.: Dwg. No.12-0164



| SGS-THOMSON MICROELECTRONICS | | |
|------------------------------|----------------------|----------------------|
| | MINIMUM Inches/mm | MAXIMUM Inches/mm |
| A | .220/5,59 | .230/5,84 |
| B | | 1.050/26,67 |
| C | .545/13,84 | .555/14,10 |
| D | .495/12,57 | .505/12,83 |
| E | .003/0,08 | .007/0,18 |
| F | | .830/21,08 |
| G | .185/4,70 | .198/5,03 |
| H | .497/12,62 | .530/13,46 |
| | | |
| | | |

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